## NSN 5961-00-878-8199

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View Online at https://aerobasegroup.com/nsn/5961-00-878-8199 **Inclosure Material:** Metal **Overall Length:** 0.672 inches **Overall Diameter:** 0.505 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Internal Junction Configuration:** Npn **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 125.0 collector to base voltage, dc and 100.0 collector to emitter voltage, dc and 8.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 2.00 amperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 4 tab, solder lug Shelf Life: N/a **Unit Of Measure:** 

No

**Demilitarization:** 

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